

Non-destructive Imaging for Advanced Packaging

ZEISS Xradia 515 Versa 3D X-ray Microscope



ZEISS Xradia 515 Versa 3D X-ray microscope (XRM) is the most cost-effective model of the Versa XRM family, with resolution maintained for large samples. With the best-in-class Versa platform, it enables high resolution

and non-destructive imaging capabilities for semiconductor package development and failure analysis.

The workhorse for 3D imaging

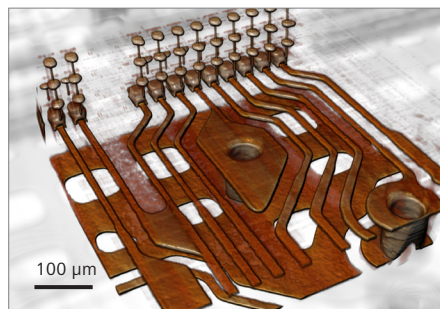
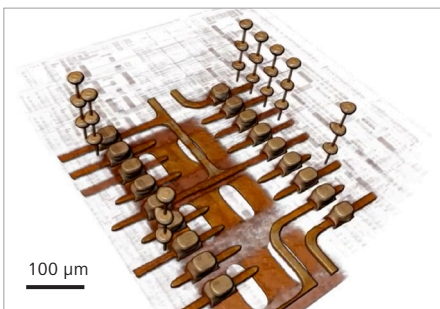
ZEISS X-ray microscopes remove major technical hurdles for 3D imaging, achieving high contrast and submicron resolution. Xradia 515 Versa uses a unique two-stage magnification technique that enables you to achieve Resolution at a Distance (RaAD).

Combined with the flexibility and stability of the Versa XRM platform, this unparalleled versatility ensures high image quality and fast time-to-results.

These 3D imaging innovations empower a broad range of applications with diverse sample sizes, geometries, and compositions. The versatility enables vital capabilities like interior tomography, phase contrast, *in situ* imaging and correlative FIB-SEM workflows. ZEISS 3D X-ray microscopes are built on upgradeable, extendable, and reliable platforms that help protect your capital investment.

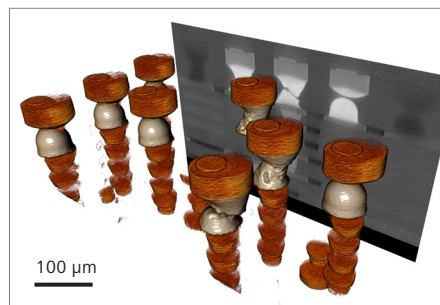
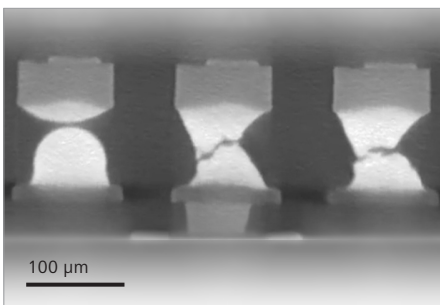
AI-powered Reconstruction for High-throughput Imaging

The optional ZEISS DeepRecon Pro module delivers 4X faster scan time and improves image quality.



3D XRM images of stacked die package interconnects in a commercial DDR4 DRAM package.

ZEISS DeepScout module enables high-resolution recovery at large fields of view (FOV), saving numerous long scans to cover the FOV.



Solder non-wets and cracks in flip chip package visible in a 2D virtual slice (left) and extracted from a 3D XRM dataset (right).



Seeing beyond

Benefits

- Non-destructive 3D imaging
- Visualize buried defects and structures
- Reduce the need for physical cross-sections
- Guide correlated FIB and SEM workflows
- Achieve high failure analysis success rates
- RaaD for highest resolution at the largest working distance from source (unique to ZEISS)
- Proprietary ZEISS optics provide high contrast
- Motorized sample positioning for efficient multi-site imaging
- SmartShield for sample protection and setup optimization
- Scout-and-Scan control system for easy-to-use workflow set-up, ideal in multi-user environments
- Program up to 14 samples at a time to run sequentially with optional Autoloader
- XRM Python API for customized instrument control
- Continuous access to advanced reconstruction technologies such as DeepRecon Pro and DeepScout for enhanced performance (e.g., throughput, image quality)

Specifications

| | ZEISS Xradia 515 Versa | ZEISS VersaXRM 615 | ZEISS VersaXRM 730 |
|---|--------------------------------------|-----------------------------|---------------------------|
| Imaging | | | |
| Spatial Resolution ^[a] | 0.5 µm | 0.5 µm | 0.45 µm |
| Resolution Performance (ZEISS resolution target at 160 kV/LE6) | | | 0.5 µm |
| Resolution at a Distance (RaaD) ^[b] (at 50 mm working distance) | 1.0 µm | 1.0 µm | 0.7 µm |
| Resolution at a Distance (RaaD) ^[b] (at 100 mm working distance) | | | 0.75 µm |
| Minimum Achievable Voxel ^[c] | 70 nm | 40 nm | 40 nm |
| X-ray Source | | | |
| Architecture | Sealed transmission, fast activation | | |
| Voltage Range | Spot size stable, 30-160 kV | | |
| Maximum Power Output | 10 W | 25 W | 25 W |
| Detector System | | | |
| ZEISS X-ray microscopes feature an innovative detector turret with multiple objectives at different magnifications. Each objective features optimized scintillators that deliver the highest absorption contrast details. | | | |
| Standard Objectives | 0.4x, 4x, 20x | 0.4x, 4x, 20x | 0.4x, 4x, 20x |
| Optional Objectives | 40x, FPX | 40x, FPX | FPX, 40x-P ^[d] |
| Flat Panel Detector | Optional, Step Mode | Optional, FAST or Step Mode | |
| Stages | | | |
| Sample Stage, load capacity | 25 kg | | |
| Sample Stage Travel, X, Y, Z | 50 mm, 100 mm, 50 mm | | |
| Stage Travel, rotation | 360° | | |
| Source Travel, Z direction | 190 mm | | |
| Detector Travel, Z direction | 290 mm | | |
| Versa Features | | | |
| Scout-and-Scan Control System | ■ | ZEN navx | ZEN navx |
| SmartShield | SmartShield | SmartShield (Lite) | SmartShield (Lite) |
| Automated Filter Changer | | | ■ |
| High Aspect Ratio Tomography (HART) | | | ■ |
| Autoloader | Optional | Optional | Optional |
| Wide Field Mode | | | 4x |
| GPU CUDA-based Reconstruction | Dual | Dual | Dual |
| Advanced Reconstruction Toolbox | | | |
| DeepRecon Pro (2-year license) | Optional 1 year or perpetual license | ■ | ■ |
| High Performance Workstation | Optional | ■ | ■ |

[a] Spatial resolution measured with ZEISS XRM 2D resolution target, normal field mode, optional 40x or 40x-Prime objective.

[b] RaaD working distance defined as clearance around axis or rotation.

[c] Voxel is a geometric term that contributes to but does not determine resolution, and is provided here only for comparison. ZEISS specifies resolution via spatial resolution, the true overall measurement of instrument resolution.

[d] 40x-Prime objective



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